

SIA426DJ-T1-GE3

SIA426DJ-T1-GE3 Information



SIA426DJ-T1-GE3
Vishay Siliconix
Discrete Semiconductor Products Transistors - FETs, MOSFETs - Single
MOSFET N-CH 20V 4.5A SC70-6
PowerPAK? SC-70-6
For the pricing/inventory/lead time, please contact us Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

For Reference Only

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



SIA426DJ-T1-GE3 Specifications

Manufacturer Part Number	SIA426DJ-T1-GE3
Manufacturer	Vishay Siliconix
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	PowerPAK? SC-70-6
Series	TrenchFET?
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	20V
Current - Continuous Drain (Id) @ 25°C	4.5A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	2.5V, 10V
Vgs(th) (Max) @ Id	1.5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	27nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	1020pF @ 10V
Vgs (Max)	±12V
FET Feature	-
Power Dissipation (Max)	3.5W (Ta), 19W (Tc)
Rds On (Max) @ Id, Vgs	23.6 mOhm @ 9.9A, 10V
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Surface Mount
Supplier Device Package	PowerPAK? SC-70-6 Single
Package / Case	PowerPAK? SC-70-6
	Report errors?

SIA426DJ-T1-GE3 Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

SIA426DJ-T1-GE3 Payment Methods



SIA426DJ-T1-GE3 Shipping Methods



If you have any question about SIA426DJ-T1-GE3, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com